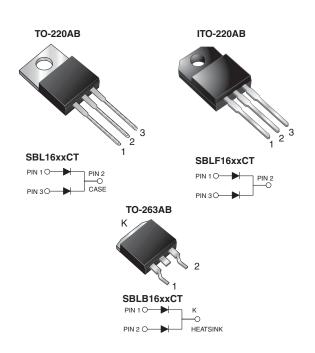
SBL(F,B)1630CT, SBL(F,B)1640CT

Vishay General Semiconductor

Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	8 A x 2				
V_{RRM}	30 V, 40 V				
I _{FSM}	250 A				
V _F	0.55 V				
T _J max.	125 °C				

FEATURES

- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- · High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix

meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PARAMETER		SYMBOL	SBL1630CT	SBL1640CT	UNIT	
Maximum repetitive peak reverse voltage Working peak reverse voltage		V _{RRM}	30	40		
		V_{RWM}	21	28	V	
Maximum DC blocking voltage		V _{DC}	30	40		
Maximum average forward rectified current at $T_C = 95$ °C	total device	1	16 8.0		A	
	per diode	I _{F(AV)}				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	250			
Operating junction and storage temperature range		T _J , T _{STG}	- 40 to + 125		°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500		V	



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	8.0 A		0.55	V	
Maximum instantaneous reverse current at DC blocking	I _R ⁽²⁾	Rated V _R	T _C = 25 °C	0.5	- mA	
voltage per diode (1)			T _C = 100 °C	50		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	SBL	SBLF	SBLB	UNIT	
Typical thermal resistance from junction to case per diode	$R_{ hetaJC}$	2.0	4.0	2.0	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	SBL1630CT-E3/45	1.85	45	50/tube	Tube	
ITO-220AB	SBLF1630CT-E3/45	1.99	45	50/tube	Tube	
TO-263AB	SBLB1630CT-E3/45	1.35	45	50/tube	Tube	
TO-263AB	SBLB1630CT-E3/81	1.35	81	800/reel	Tape and reel	
TO-220AB	SBL1630CTHE3/45 (1)	1.85	45	50/tube	Tube	
ITO-220AB	SBLF1630CTHE3/45 (1)	1.99	45	50/tube	Tube	
TO-263AB	SBLB1630CTHE3/45 (1)	1.35	45	50/tube	Tube	
TO-263AB	SBLB1630CTHE3/81 (1)	1.33	81	800/reel	Tape and reel	

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

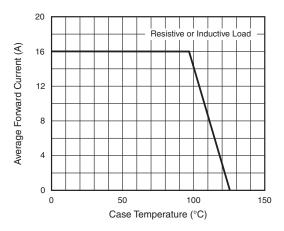


Fig. 1 - Forward Current Derating Curve

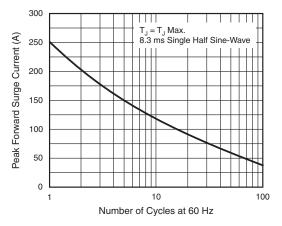


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

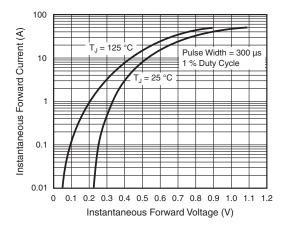


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

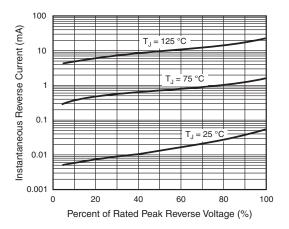


Fig. 4 - Typical Reverse Characteristics Per Diode

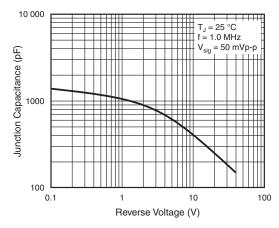


Fig. 5 - Typical Junction Capacitance Per Diode

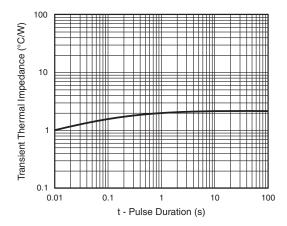
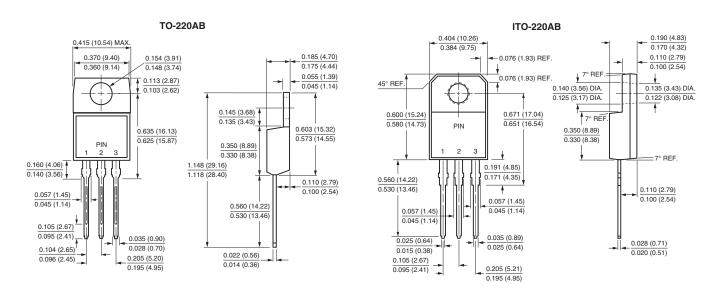


Fig. 6 - Typical Transient Thermal Impedance Per Diode

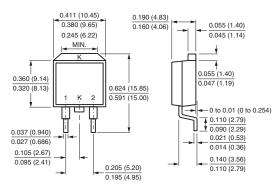
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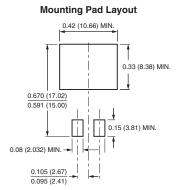
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB







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